

**TOSHIBA**

**TA2120FN**

TENTATIVE TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

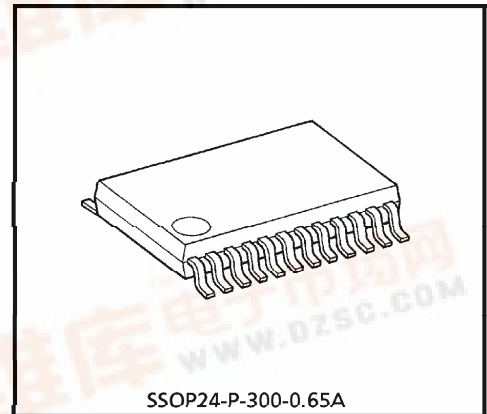
# TA2120FN

## LOW CONSUMPTION CURRENT STEREO HEADPHONE POWER AMPLIFIER FOR PORTABLE CD (3V USE)

The TA2120FN is a low consumption current stereo headphone power amplifier developed for portable CD players (3V). This IC has active bass boost, output limiter, input pin for beep sound.

### FEATURES

- Low consumption current :  $I_{CCQ} = 1.9\text{mA}$  (C-CUP) (typ.)  
 $I_{CCQ} = 2.6\text{mA}$  (OCL) (typ.)
- Two kinds of gain mode available :  $G_V = 16\text{dB}$  or  $8.5\text{dB}$
- Output power ( $V_{CC} = 2.0\text{V}$ ,  $f = 1\text{kHz}$ ,  $\text{THD} = 10\%$ ,  $R_L = 16\Omega$ )  
 $P_o = 8\text{mW}$  (typ.)
- Low noise :  $V_{NO} = -98\text{dBV}$  (typ.)
- Built-in the center amplifier ON/OFF function.  
(Favorable for low dissipation current in the C-Couple output configuration)
- Built-in active bass boost system
- Built-in output limiter function
- Input pin for beep sound
- Excellent ripple rejection ratio
- Built-in capacitor for reducing buzz noise
- Built-in power mute
- Built-in a power on/off switch
- Operating supply voltage range ( $T_a = 25^\circ\text{C}$ ) :  $V_{CC}(\text{opr}) = 1.8 \sim 4.5\text{V}$

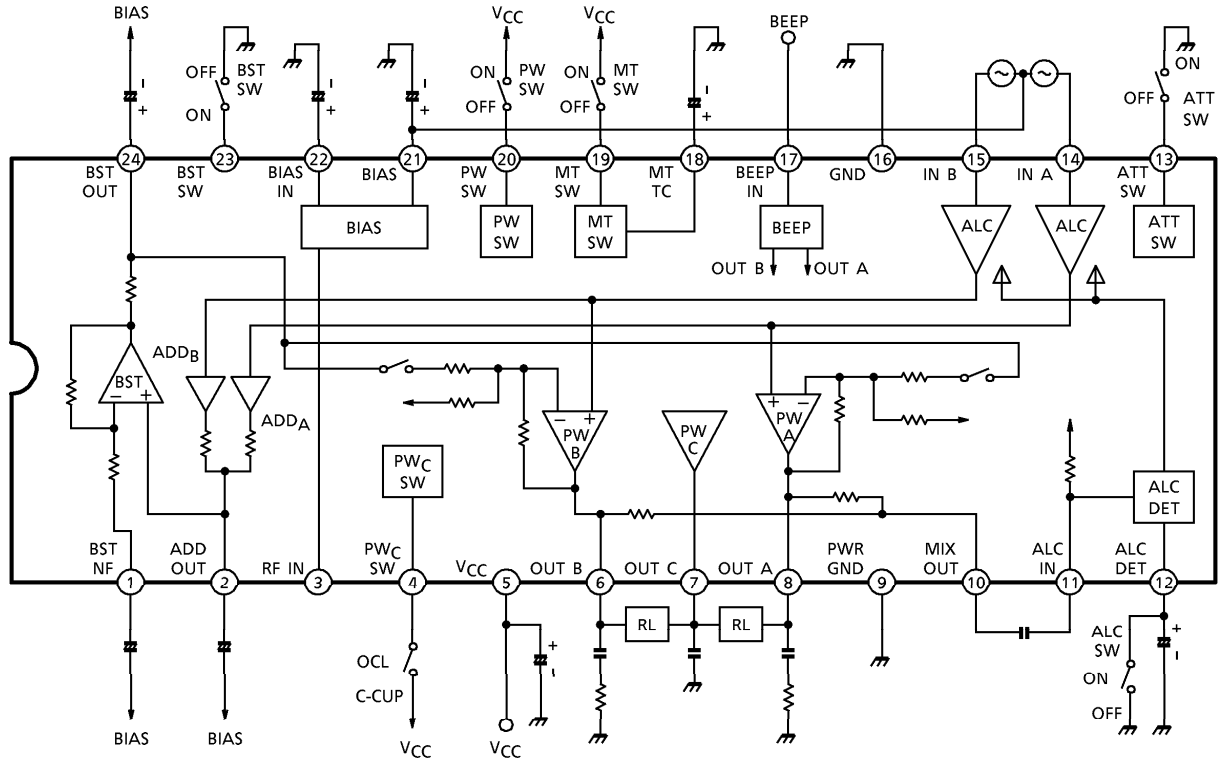


Weight : 0.14g (Typ.)

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BLOCK DIAGRAM



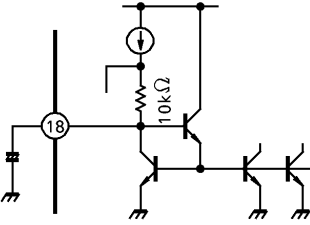
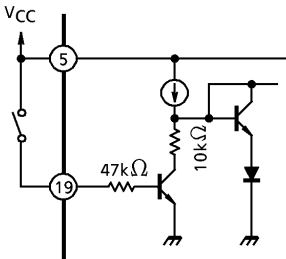
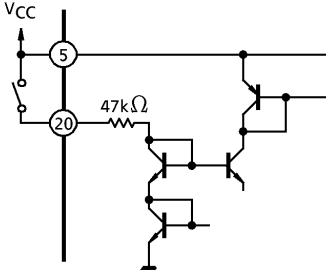
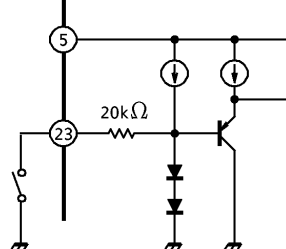
**TERMINAL EXPLANATION**

(Terminal voltage : Typical terminal voltage at no signal with test circuit,  $V_{CC} = 2.4V$ ,  $T_a = 25^\circ C$ )

TERMINAL		FUNCTION	INTERNAL CIRCUIT	TERMINAL VOLTAGE (V)
No.	NAME			
1	BST NF	NF of BST amplifier		0.85
24	BST OUT	Output of BST amplifier (Terminal for filter)		0.85
2	ADD OUT	Output of ADD amplifier (Terminal for filter)		0.85
3	RF IN	Terminal for ripple filter circuit		1.44
21	BIAS	BIAS voltage		0.85
22	BIAS IN	Filter terminal for BIAS circuit		0.85

TERMINAL		FUNCTION	INTERNAL CIRCUIT	TERMINAL VOLTAGE (V)
No.	NAME			
4	PW <sub>C</sub> SW	Center amplifier on / off switchover  (V <sub>CC</sub> : Center amplifier off (C-Couple) OPEN : Center amplifier on (OCL))		—
7	OUT <sub>C</sub>	Output of center amplifier (Common terminal for OCL output configuration)		0.85
5	V <sub>CC</sub>	—	—	2.4
6	OUT <sub>B</sub>	Output of power amplifier		0.85
8	OUT <sub>A</sub>			0.85
14	IN <sub>A</sub>	Input of power amplifier		0.85
15	IN <sub>B</sub>			0.85
10	MIX OUT	Output of power amplifier (Mixed)		0.85

TERMINAL		FUNCTION	INTERNAL CIRCUIT	TERMINAL VOLTAGE (V)
No.	NAME			
9	PWR GND	GND of power amplifier	—	0
11	ALC IN	Input terminal for ALC detector circuit		0.85
12	ALC DET	Smoothing for ALC detection, ALC on/off switchover (GND : ALC off OPEN : ALC on)		—
13	ATT SW	Power amplifier gain switchover (OPEN/V <sub>CC</sub> : ATT off (G <sub>V</sub> = 16dB) GND : ATT on (G <sub>V</sub> = 8.5dB)		—
16	GND	GND of input stage in power amplifier	—	0
17	BEEP IN	Input terminal for Beep sound It receive beep sound from microcomputer. And power amplifier outputs this beep sound.		0

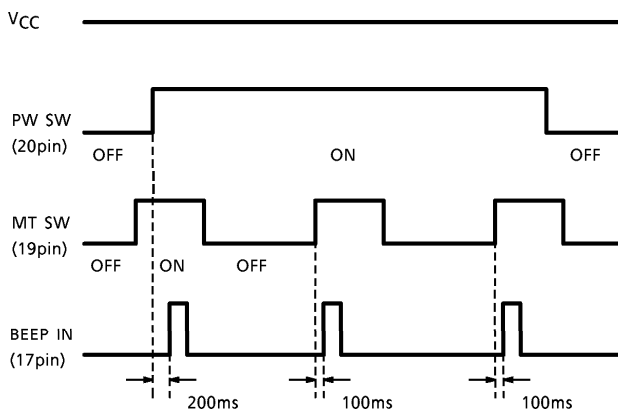
TERMINAL		FUNCTION	INTERNAL CIRCUIT	TERMINAL VOLTAGE (V)
No.	NAME			
18	MT TC	Terminal of mute smoothing Smoothing for shock noise at power muting switch over		1.4
19	MT SW	Power mute switchover (GND / OPEN : Mute off VCC : Mute on)		—
20	PW SW	Power on / off switchover (VCC : Power on GND / OPEN : Power off)		—
23	BST SW	Bst on / off switchover (BST on : OPEN / VCC BST off : GND)		—

**APPLICATION NOTE**

1. Beep Sound

Beep sound signals from, for example, a micro controller can be received through the beep input pin 17. At power mute mode,  $PW_A$  and  $PW_B$  are turned off. The current of the beep signal input to be via beep amplifier is amplified at the output stage of  $PW_A$  and  $PW_B$ . The output from beep amplifier becomes the constant voltage source. As a result, the beep sound is output to the headphone load.

If the input signal for beep (Pin 17) is not, this terminal should be fixed GND level.



2. Power Switch

As long as the power switch is not connect to  $V_{CC}$ , the IC does not operate. If external noise causes malfunctions, we recommend to connect a pull-down resistor externally (Sensitivity of the power mute switch is high).

3. Center Amplifier ( $PW_C$ )

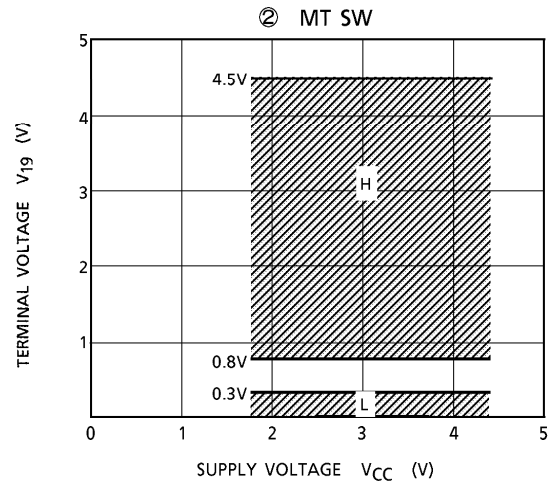
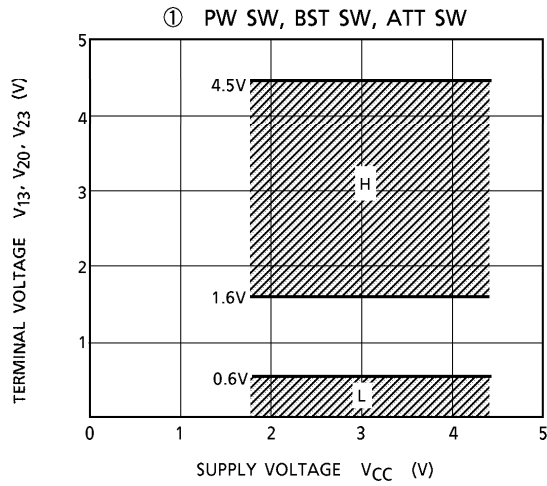
Terminal for  $PW_C$  output is common terminal for OCL output configuration.  $PW_C$  ON/OFF mode is controlled by  $PW_C$  switch (Pin 4). To reduce the consumption current,  $PW_C$  should be turned off by this switch.

$PW_C$  SW ( OPEN : OCL  
                   $V_{CC}$  : C-Couple

4. Terminal of RF IN (3pin)

Adding Capacitor (Recommendation :  $10\mu F$ ) to terminal of RF IN (Pin 3), the ripple rejection ratio is improved by secondly ripple filter (In the C-Couple output configuration , this capacitor should be connected.)

5. Threshold Voltage of Each Switches



	PW SW ( $V_{20}$ )
'H'	OPERATING
'L' OPEN	IC OFF

	MT SW ( $V_{19}$ )
'H'	MUTE ON
'L' OPEN	MUTE OFF

	ATT SW ( $V_{13}$ )	BST SW ( $V_{23}$ )
'H' OPEN	ATT OFF	BST ON
'L'	ATT ON	BST OFF

6. Exterminal capacitor

These capacitors which are prevent oscillation of power amplifier and de-coupled at terminals of BIAS and  $V_{CC}$  need to be small temperature coefficient and excellent frequency characteristic.



**MAXIMUM RATINGS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	4.5	V
Output Current	I <sub>o</sub> (peak)	100	mA
Power Dissipation	P <sub>D</sub> (Note)	550	mW
Operating Temperature	T <sub>opr</sub>	-25~75	°C
Storage Temperature	T <sub>stg</sub>	-55~150	°C

(Note) Deleted above 25°C in the proportion of 4.4mW/1°C.

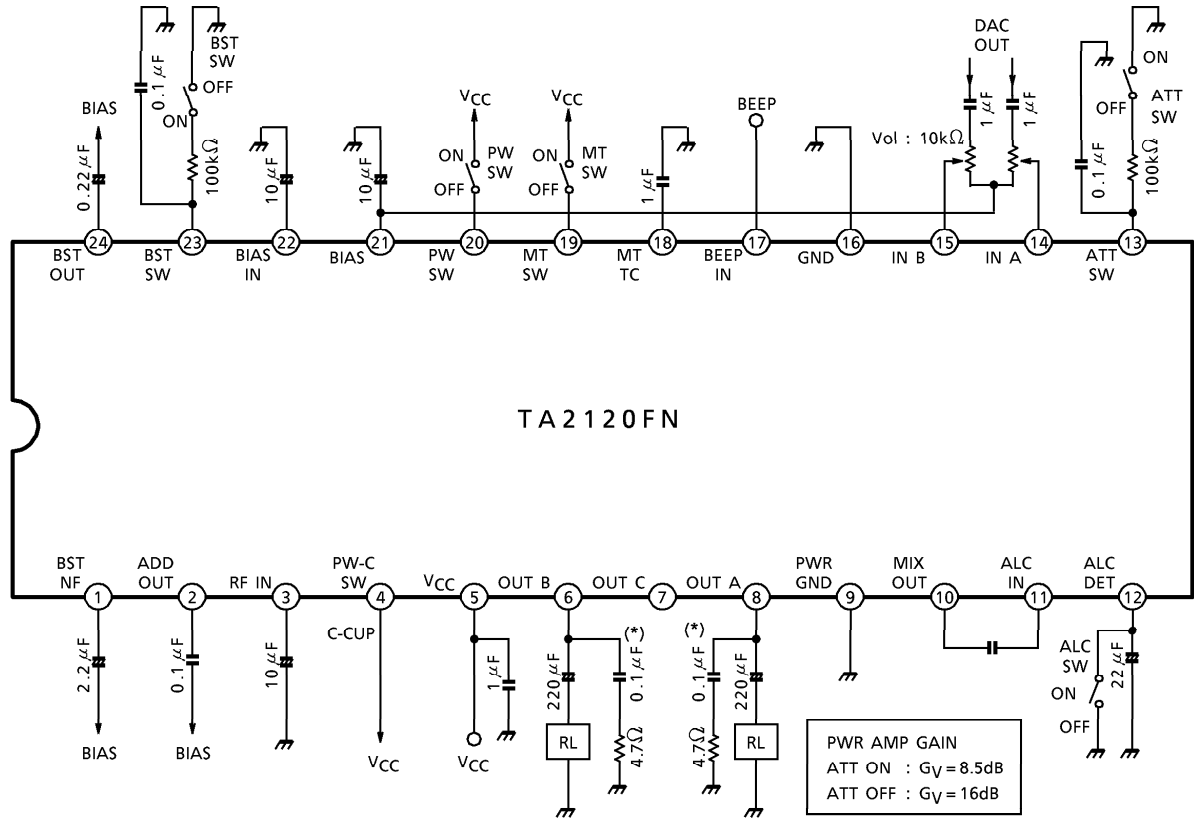
**ELECTRICAL CHARACTERISTICS**

(Unless otherwise specified : V<sub>CC</sub> = 2.4V, R<sub>g</sub> = 600Ω, R<sub>L</sub> = 16Ω, f = 1kHz, Ta = 25°C  
 SW1 : a, SW2 : a, SW3 : OPEN, SW4 : a, SW5 : a, SW6 : OPEN, SW7 : ON,  
 SW8 : ON

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Quiescent Supply Current		I <sub>CC1</sub>	—	IC OFF (C-Couple) SW1 : b, SW2 : b, SW3 : ON	—	0.1	5	μA
		I <sub>CC2</sub>		IC OFF (OCL) SW1 : b, SW2 : b	—	0.1	5	μA
		I <sub>CC3</sub>		MUTE ON (C-Couple) SW2 : b, SW3 : ON	—	1	2	mA
		I <sub>CC4</sub>		MUTE ON (OCL) SW2 : b	—	1.7	3	mA
		I <sub>CC5</sub>		No signal (C-Couple) SW3 : ON	—	1.9	3.5	mA
		I <sub>CC6</sub>		No signal (OCL)	—	2.6	4.5	mA
Consumption Supply Current		I <sub>CC7</sub>	—	P <sub>o</sub> = 0.5mW + 0.5mW (C-Couple), SW3 : ON	—	6.6	—	mA
		I <sub>CC8</sub>	—	P <sub>o</sub> = 0.5mW + 0.5mW (OCL)	—	12.1	—	mA
Power Amplifier Stage	Voltage Gain (1)	G <sub>V1</sub>	—	V <sub>o</sub> = -22dBV, SW6 : GND	5.5	8.5	10.5	dB
	Voltage Gain (2)	G <sub>V2</sub>	—	V <sub>o</sub> = -22dBV	14	16	18	dB
	Output Power	P <sub>omax</sub>	—	THD = 10%, V <sub>CC</sub> = 2.0V	5	8	—	mW
	Total Harmonic Distortion	THD	—	V <sub>o</sub> = -12.2dBV	—	0.1	0.5	%
	Output Noise Voltage	V <sub>no</sub>	—	R <sub>g</sub> = 600Ω, Filter : IHF-A, SW5 : b	—	-98	-92	dBV
	Crosstalk	CT	—	V <sub>o</sub> = -12.2dBV	24	40	—	dB
	Ripple Rejection Ratio	RR	—	V <sub>CC</sub> = 1.8V, fr = 100Hz, Vr = -20dBV	69	75	—	dB
	Mute Attenuation	MUTE	—	V <sub>o</sub> = -12.2dBV, SW2 : b	80	90	—	dB
	Beep Voltage	VBEEP	—	V Beep IN = 0dBV, SW2 : b	-56	-51	-46	dBV
Boost Gain	Bst	—	V <sub>o</sub> = -30dBV, f = 100Hz, SW7 : ON→OPEN	9	11.5	14	dB	
Output Limiter Level	V <sub>ALC</sub>	—	V <sub>in</sub> = -20dBV, SW8 : OPEN	-41.5	-39.5	-37.5	dBV	

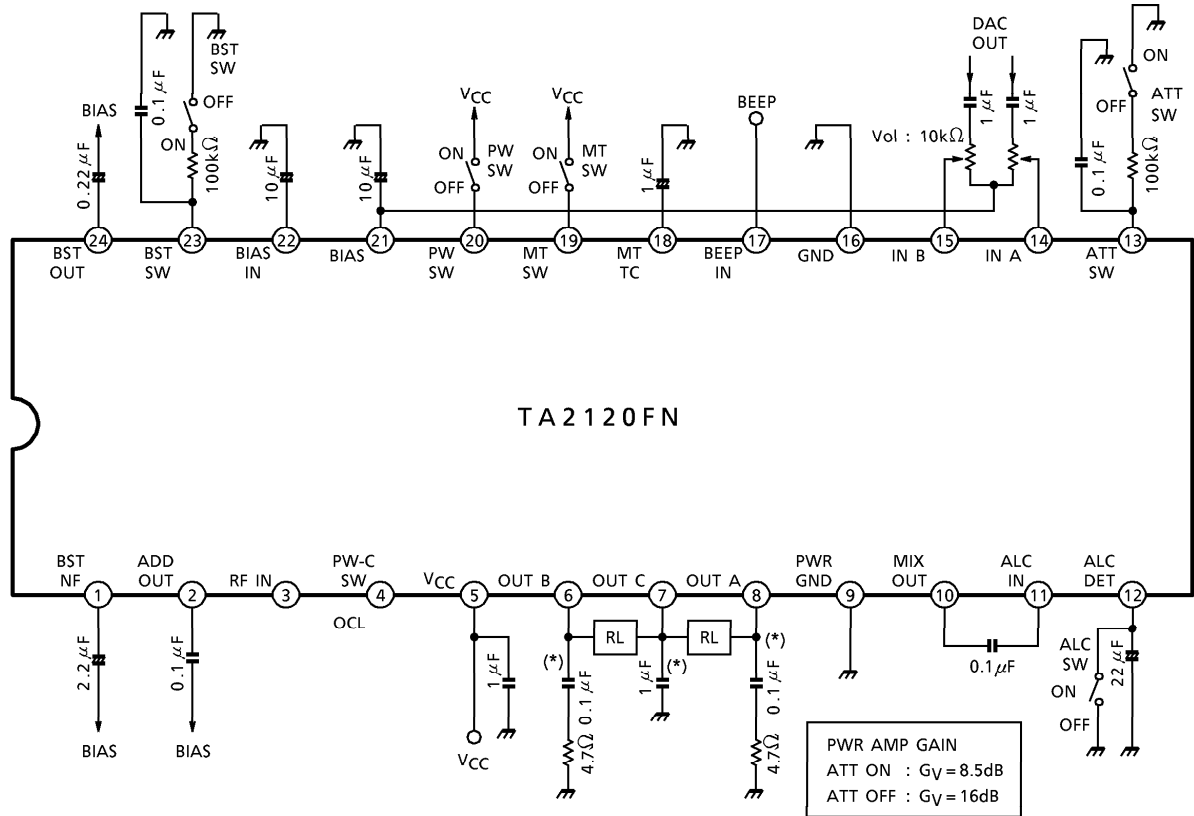


APPLICATION CIRCUIT 1 (C-Couple MODE)



(\*) MONOLITHIC CERAMIC CAPACITOR

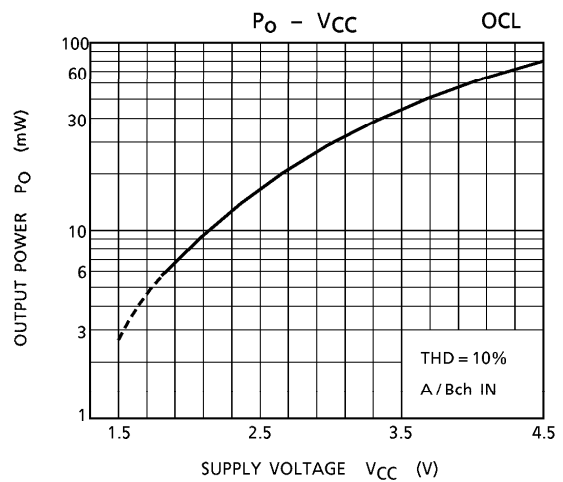
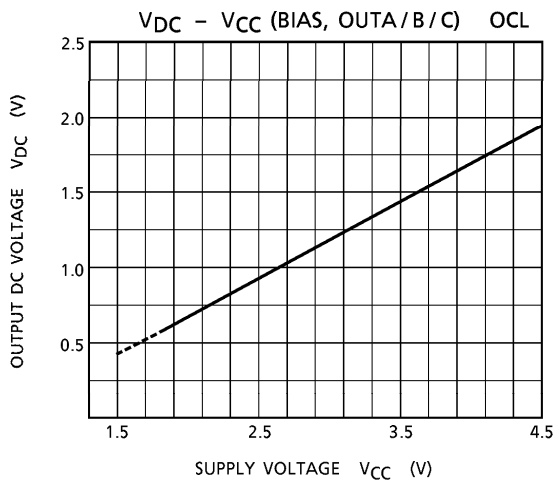
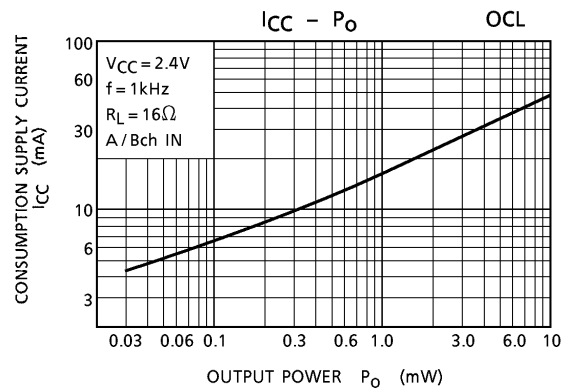
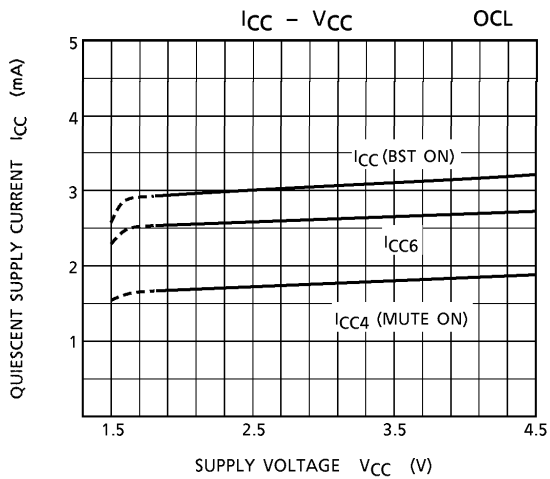
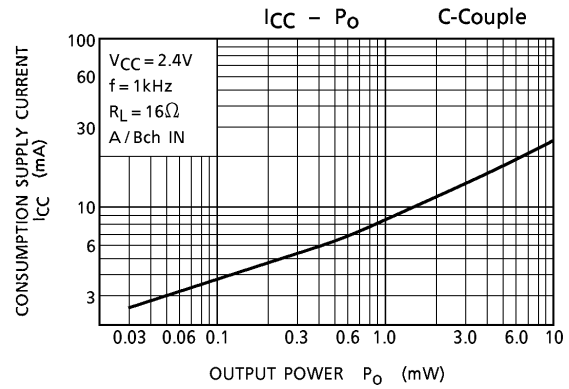
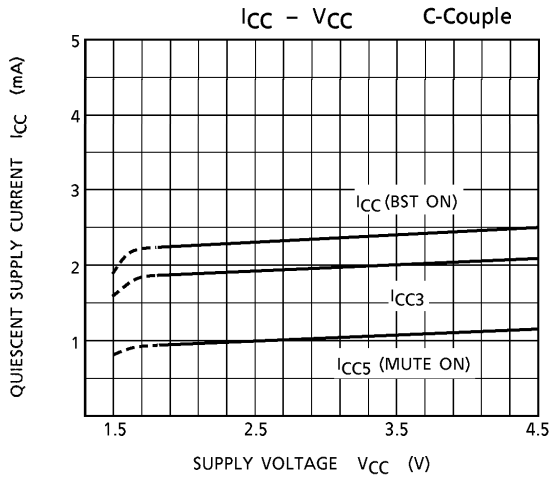
APPLICATION CIRCUIT 2 (OCL MODE)

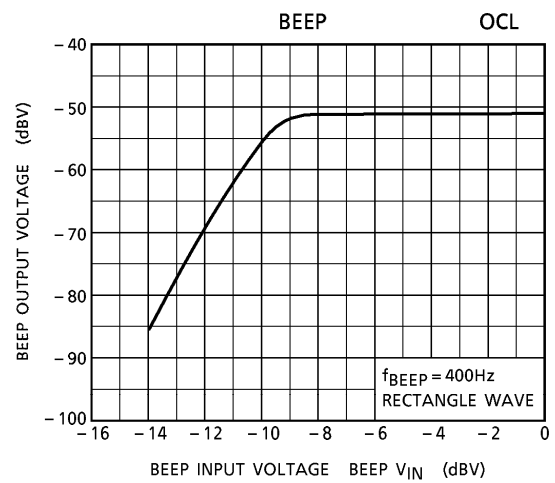
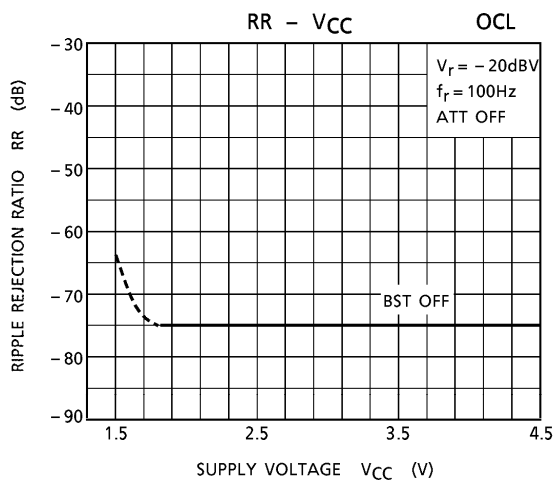
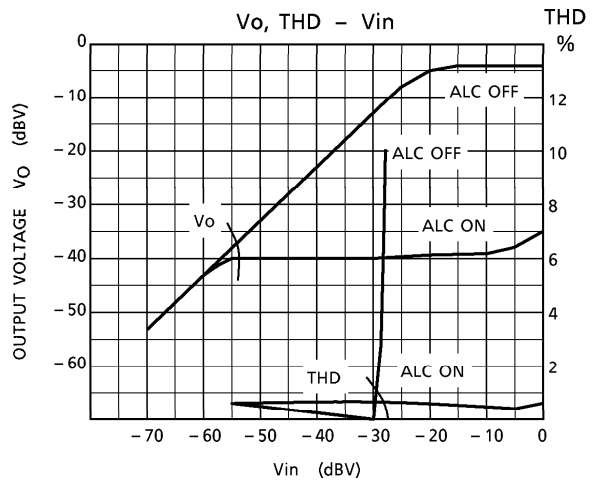
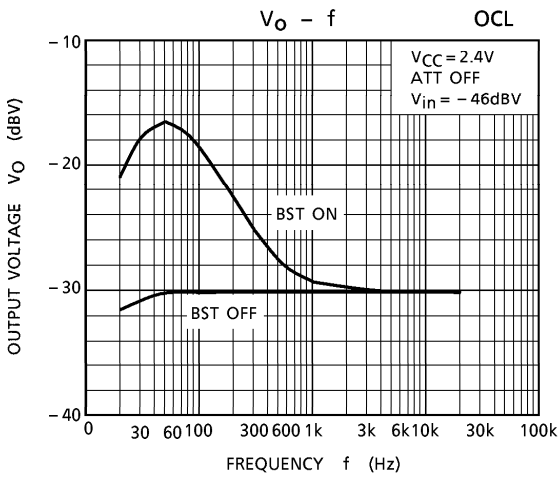
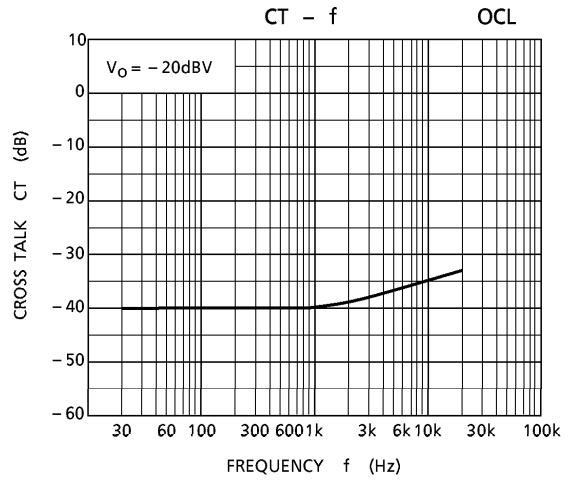
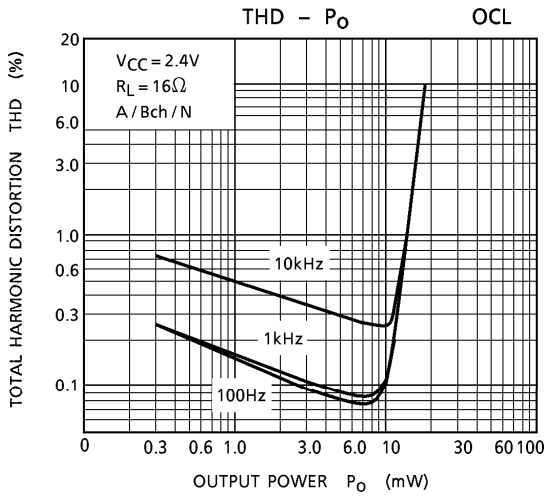


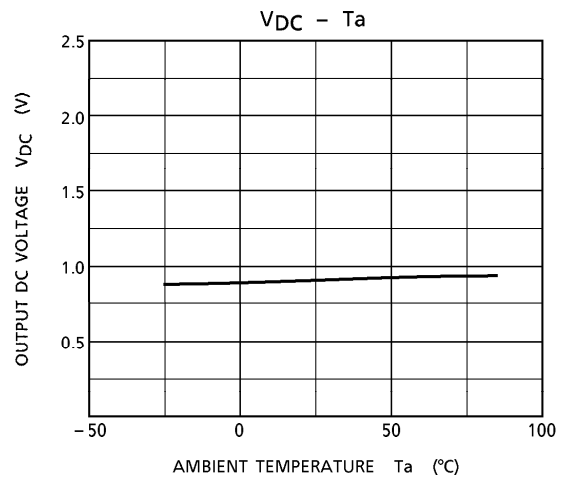
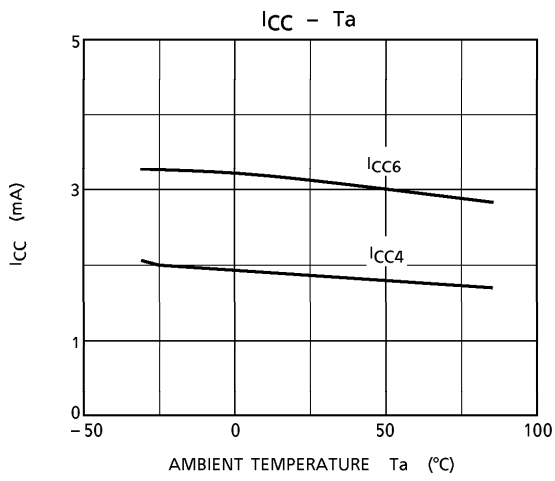
(\*) MONOLITHIC CERAMIC CAPACITOR

CHARACTERISTICS

(Unless otherwise specified :  $V_{CC} = 2.4V$ ,  $R_L = 16\Omega$ ,  $R_g = 600\Omega$ ,  $f = 1kHz$ ,  $T_a = 25^\circ C$ , OCL, ATT OFF)

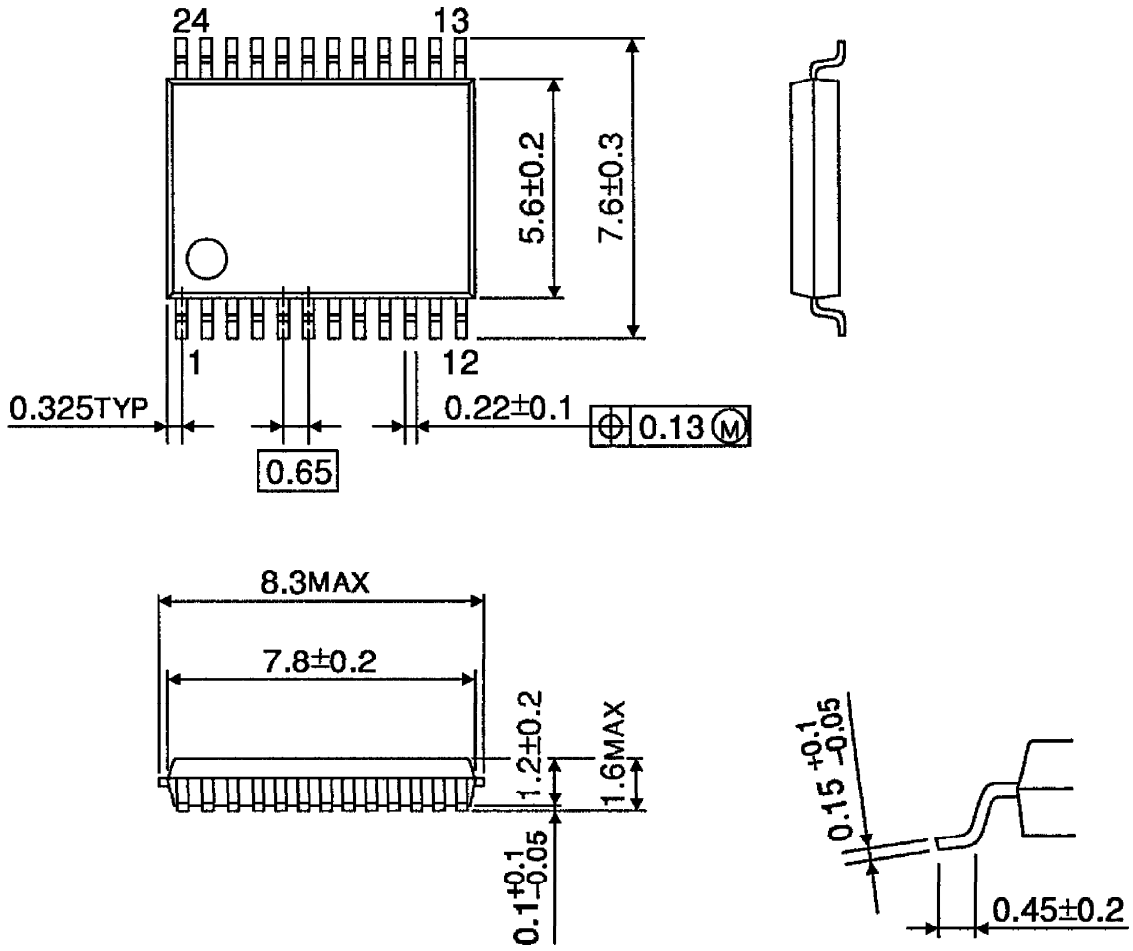






**OUTLINE DRAWING**  
SSOP24-P-300-0.65A

Unit : mm



Weight : 0.14g (Typ.)